



January 2015

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### 1.0A SURFACE MOUNT SUPER-FAST RECTIFIER

### **Features**

- Glass Passivated Die Construction
- Super-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 30A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free "Green" Device (Note 3)

## **Mechanical Data**

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (§3)
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.064 grams (Approximate)





Top View

**Bottom View** 

### Ordering Information (Note 4)

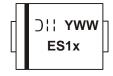
Part Number	Case	Packaging
ES1x-13-F	SMA	5000/Tape & Reel

<sup>\*</sup> x = Device type, e.g. ES1A-13-F

Notes

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



ES1x = Product type marking code, ex. ES1A

| | = Manufacturer's code marking

| YWW = Date code marking
| Y = Last digit of year (ex: 2 for 2002)

| WW = Week code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	ES1A	ES1B	ES1C	ES1D	ES1G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 6)	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	400	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	105	140	280	V
Average Rectified Output Current @ T <sub>T</sub> = +110°C	lo			1.0			Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load				30			Α

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal (Note 5)	R <sub>θJT</sub>	25	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

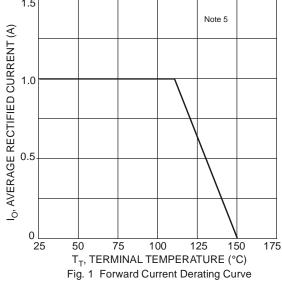
# $\textbf{Electrical Character} \underline{\textbf{istics}} \ (@T_{A} = +25 ^{\circ} \texttt{C}, \ \textbf{unless otherwise specified.})$

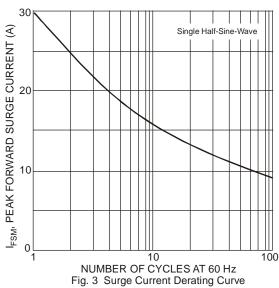
Characteristic		Symbol	ES1A	ES1B	ES1C	ES1D	ES1G	Unit
Minimum Reverse Breakdown Voltage (Note 6)	$I_R = 5\mu A$	$V_{(BR)R}$	50	100	150	200	400	V
Maximum Forward Voltage Drop	I <sub>F</sub> = 0.6A I <sub>F</sub> = 1.0A	V <sub>FM</sub>		_	90 92		 1.25	V
Peak Reverse Current at Rated DC Blocking Voltage (Note 6)	$T_A = +25^{\circ}C$ $T_A = +125^{\circ}C$	I <sub>RM</sub>	5.0 200			μA		
Maximum Reverse Recovery Time (Note 7)		t <sub>RR</sub>			25			ns
Typical Total Capacitance (Note 8)		Ст			20			pF

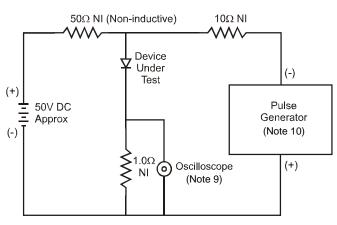
Notes:

- 5. Unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pad as heat sink.
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Measured with  $I_F$  = 0.5A,  $I_R$  = 1.0A,  $I_{RR}$  = 0.25A. See figure 5. 8. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.



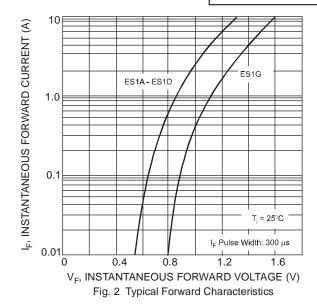


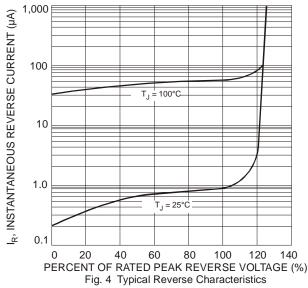


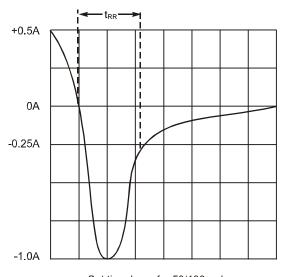


Notes:

9. Rise Time = 7.0ns max. Input Impedance = 1.0M $\Omega$ , 22pF. 10.Rise Time = 10ns max. Input Impedance = 50 $\Omega$ .







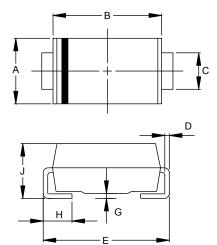
Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit



## **Package Outline Dimensions**

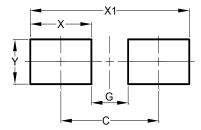
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SMA					
Dim	Min	Max			
Α	2.29	2.92			
В	4.00	4.60			
С	1.27	1.63			
D	0.15	0.31			
Е	4.80	5.59			
G	0.05	0.20			
Н	0.76	1.52			
J	1.96	2.40			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value		
Dimensions	(in mm)		
С	4.00		
G	1.50		
X	2.50		
X1	6.50		
γ	1.70		



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